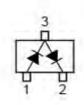


BAV99 SWITCHING DIODES

FEATURES

Fast Switching Speed
For General Purpose Switching Applications
High Conductance





Marking Code: A7 SOT-23 Plastic Package

Absolute Maximum Ratings ($T_a = 25$ °C)

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	85	V
Continuous Reverse Voltage	V_R	75	V
Continuous Forward Current (Double Diode Loaded)	I _F	125	mA
Continuous Forward Current (Single Diode Loaded)	I _F	215	mA
Repetitive Peak Forward Current	I _{FRM}	450	mA
Non-repetitive Peak Forward Surge Current at t = 1 s at t = 1 ms at t = 1 µs	I _{FSM}	0.5 1 4.5	А
Power Dissipation	P _{tot}	350	mW
Junction Temperature	T _j	150	°C
Storage Temperature Range	T _{stg}	- 65 to + 150	°C

Characteristics at T_a = 25 °C

Parameter	Symbol	Max.	Unit
Forward Voltage at $I_F = 1$ mA at $I_F = 10$ mA at $I_F = 50$ mA at $I_F = 150$ mA	V _F	0.715 0.855 1 1.25	V
Reverse Current at V_R = 25 V at V_R = 75 V at V_R = 25 V, T_j = 150 °C at V_R = 75 V, T_j = 150 °C	I _R	30 1 30 50	nA µA µA µA
Diode Capacitance at $V_R = 0$, $f = 1$ MHz	C _d	1.5	pF
Reverse Recovery Time at $I_F = I_R = 10$ mA, $I_R = 1$ mA, $R_L = 100$ Ω	t _{rr}	4	ns



Typical Characteristics

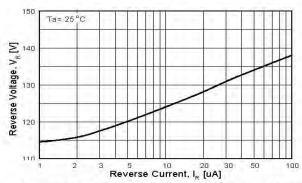


Figure 1. Reverse Voltage vs Reverse Current BV - 1.0 to 100uA

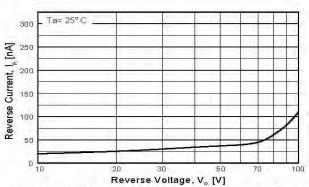


Figure 2. Reverse Current vs Reverse Voltage IR - 10 to 100 V

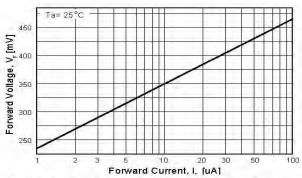


Figure 3. Forward Voltage vs Forward Current VF - 1.0 to 100 uA

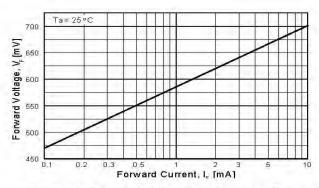


Figure 4. Forward Voltage vs Forward Current VF - 0.1 to 10 mA

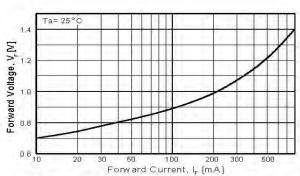


Figure 5. Forward Voltage vs Forward Current VF - 10 - 800 mA

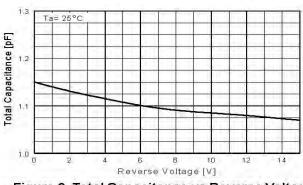
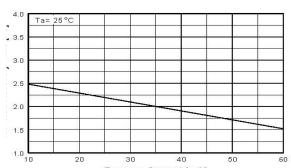


Figure 6. Total Capacitance vs Reverse Voltage



Reverse Current [mA]
Figure 7. Reverse Recovery Time
vs Reverse Current
TRR - IR 10 mA vs 60 mA

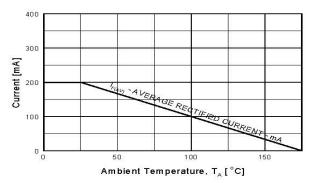


Figure 8. Average Rectified Current $(I_{F(AV)})$ versus Ambient Temperature (T_A)



PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT-23

